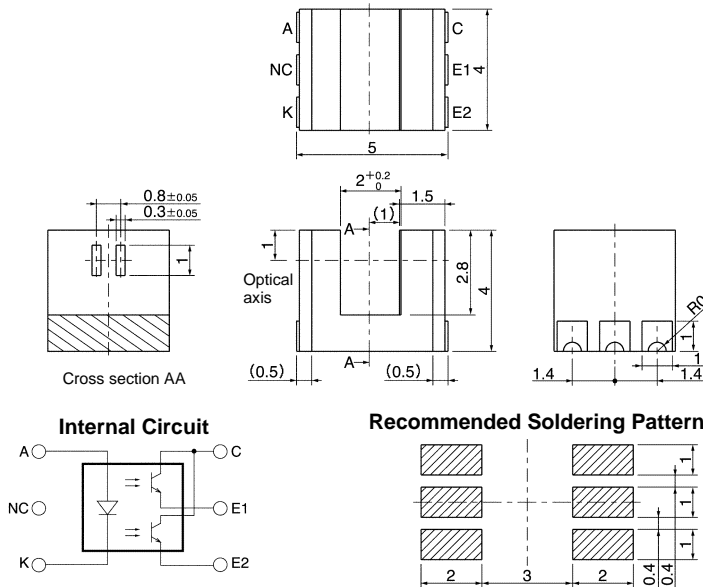


■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



Terminal No.	Name
A	Anode
NC	Not connected.
K	Cathode
C	Collector
E1	Emitter 1
E2	Emitter 2

Unless otherwise specified, the tolerances are ± 0.15 mm.

■ Features

- Ultra-compact with a 5-mm-wide sensor and a 2-mm-wide slot.
- PCB surface mounting type.
- High resolution with a 0.3-mm-wide aperture.
- Dual-channel output.

■ Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Rated value
Emitter	Forward current	I_F 25 mA (see note 1)
	Pulse forward current	I_{FP} 100 mA (see note 2)
	Reverse voltage	V_R 5 V
Detector	Collector–Emitter voltage	V_{CEO} 20 V
	Emitter–Collector voltage	V_{ECO} 5 V
	Collector current	I_C 20 mA
	Collector dissipation	P_C 75 mW (see note 1)
Ambient temperature	Operating	T_{opr} -30°C to 85°C
	Storage	T_{stg} -40°C to 90°C
	Reflow soldering	T_{sol} 240°C (see note 3)
	Manual soldering	T_{sol} 300°C (see note 3)

- Note:**
1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C .
 2. Duty: 1/100; Pulse width: 0.1 ms
 3. Complete soldering within 10 seconds for reflow soldering and within 3 seconds for manual soldering.

■ Electrical and Optical Characteristics ($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Condition
Emitter	Forward voltage	V_F	1.1 V typ., 1.3 V max.
	Reverse current	I_R	10 μA max.
	Peak emission wavelength	λ_P	940 nm typ.
Detector	Light current	I_{L1}/I_{L2}	50 μA min., 150 μA typ., 500 μA max.
	Dark current	I_D	100 nA max.
	Leakage current	I_{LEAK}	---
	Collector–Emitter saturated voltage	$V_{CE}(\text{sat})$	0.1 V typ., 0.4 V max.
	Peak spectral sensitivity wavelength	λ_P	900 nm typ.
Rising time	t_r	10 μs typ.	$V_{CC} = 5$ V, $R_L = 1$ k Ω , $I_L = 100$ μA
Falling time	t_f	10 μs typ.	$V_{CC} = 5$ V, $R_L = 1$ k Ω , $I_L = 100$ μA